

# RGW00TK65

## 650V 50A Field Stop Trench IGBT

V <sub>CES</sub>	650V
I <sub>C (100°C)</sub>	26A
V <sub>CE(sat) (Typ.)</sub>	1.5V@I <sub>C</sub> =50A
$P_D$	89W

#### Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

## Applications

**PFC** 

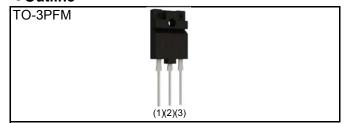
**UPS** 

Welding

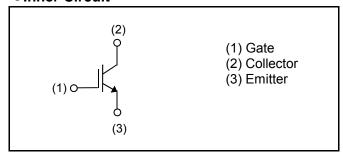
Solar Inverter

ΙH

#### Outline



#### ●Inner Circuit



Packaging Specifications

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	Packaging	Tube		
	Reel Size (mm)	-		
Typo	Tape Width (mm)	-		
Туре	Basic Ordering Unit (pcs)	450		
	Packing Code	C11		
	Marking	RGW00TK65		

## ● **Absolute Maximum Ratings** (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage		$V_{GES}$	±30	V
T <sub>C</sub> = 25°C		I <sub>C</sub>	45	А
Collector Current	T <sub>C</sub> = 100°C	I <sub>C</sub>	26	А
Pulsed Collector Current		I <sub>CP</sub> *1	200	А
$T_C = 25^{\circ}C$		P <sub>D</sub>	89	W
Power Dissipation $T_C = 100^{\circ}C$		P <sub>D</sub>	44	W
Operating Junction Temperature		T <sub>j</sub>	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-55 to +175	°C

<sup>\*1</sup> Pulse width limited by  $T_{imax}$ .

#### ●Thermal Resistance

Parameter	Symbol	Values			Unit
r ai ai iletei	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	1	-	1.67	°C/W

# ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
r ai ai iletei	Syllibol	Conditions	Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	-	-	V
Collector Cut - off Current	I <sub>CES</sub>	V <sub>CE</sub> = 650V, V <sub>GE</sub> = 0V	-	-	10	μΑ
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V, V_{CE} = 0V$	1	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 33.0 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_C = 50A$ , $V_{GE} = 15V$ $T_j = 25^{\circ}C$	-	1.5	1.9	V
		T <sub>j</sub> = 175°C	-	1.85	-	

## ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Daramatar	Cymphal	Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 30V	-	4200	-	
Output Capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0V	-	104	-	pF
Reverse Transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	79	-	
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 400V	-	141	-	
Gate - Emitter Charge	$Q_{ge}$	I <sub>C</sub> = 50A	-	30	-	nC
Gate - Collector Charge	$Q_{gc}$	V <sub>GE</sub> = 15V	-	52	-	
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 50A, V <sub>CC</sub> = 400V	-	52	-	
Rise Time	t <sub>r</sub>	$V_{GE} = 15V, R_{G} = 10\Omega$	-	21	-	
Turn - off Delay Time	t <sub>d(off)</sub>	T <sub>j</sub> = 25°C	-	180	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	33	-	
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> includes diode	-	1.18	-	
Turn - off Switching Loss	E <sub>off</sub>	reverse recovery	-	0.96	-	mJ
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 50A, V <sub>CC</sub> = 400V	-	49	-	
Rise Time	t <sub>r</sub>	$V_{GE} = 15V, R_G = 10\Omega$	-	23	-	no
Turn - off Delay Time	t <sub>d(off)</sub>	T <sub>j</sub> = 175°C	-	201	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	72	-	
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> includes diode	-	1.18	-	
Turn - off Switching Loss	E <sub>off</sub>	reverse recovery	-	1.18	-	mJ
		I <sub>C</sub> = 200A, V <sub>CC</sub> = 520V				
Reverse Bias Safe Operating Area	RBSOA	V <sub>P</sub> = 650V, V <sub>GE</sub> = 15V	FU	LL SQUA	RE	-
1		$R_G = 100\Omega, T_j = 175^{\circ}C$				

#### • Electrical Characteristic Curves

Fig.1 Power Dissipation vs. Case Temperature

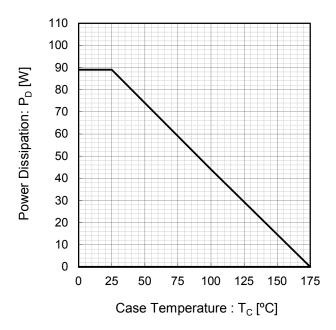


Fig.2 Collector Current vs. Case Temperature

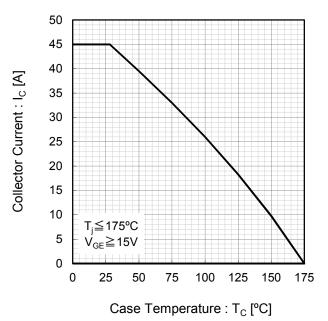


Fig.3 Forward Bias Safe Operating Area

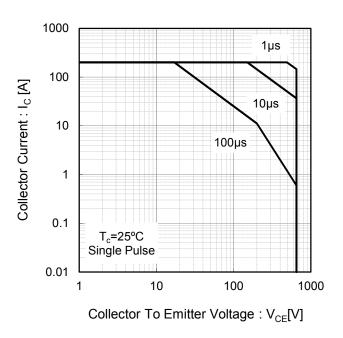
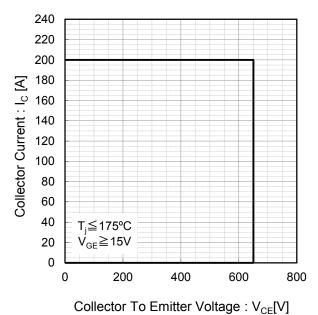


Fig.4 Reverse Bias Safe Operating Area



#### **•**Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

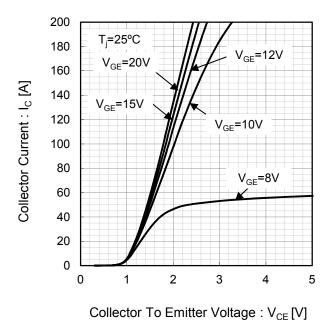
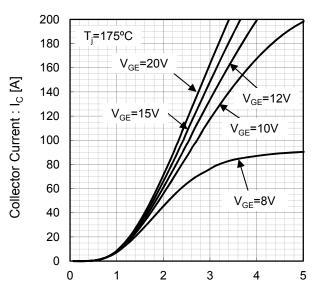


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage : V<sub>CE</sub> [V]

Fig.7 Typical Transfer Characteristics

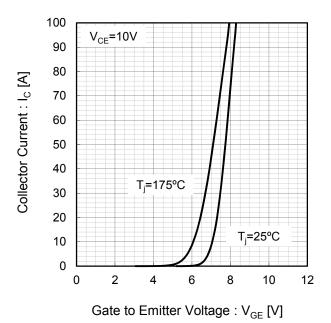
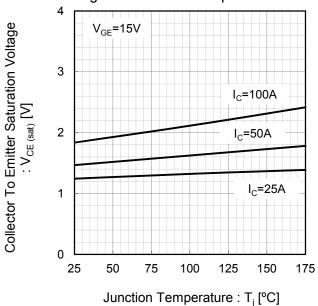


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



#### • Electrical Characteristic Curves

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

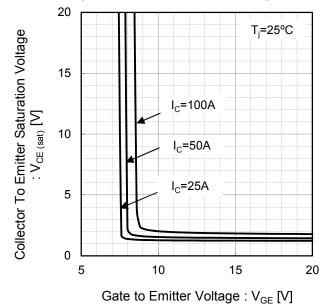
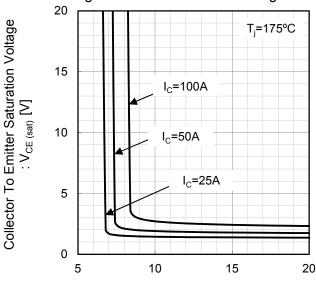


Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate to Emitter Voltage : V<sub>GE</sub> [V]

Fig.11 Typical Switching Time vs. Collector Current

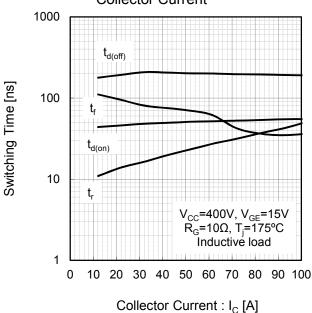
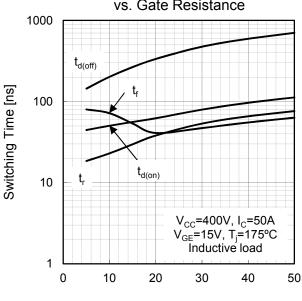


Fig.12 Typical Switching Time vs. Gate Resistance



Gate Resistance :  $R_G$  [ $\Omega$ ]

#### **•**Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs. Collector Current

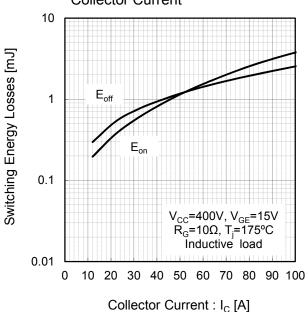


Fig.14 Typical Switching Energy Losses vs. Gate Resistance

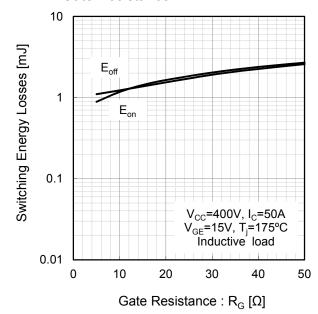
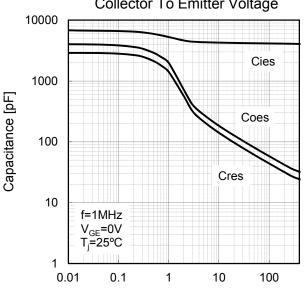
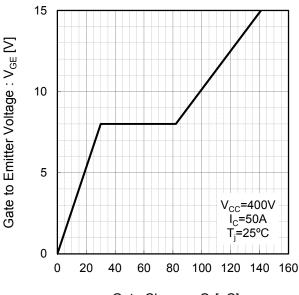


Fig.15 Typical Capacitance vs.
Collector To Emitter Voltage



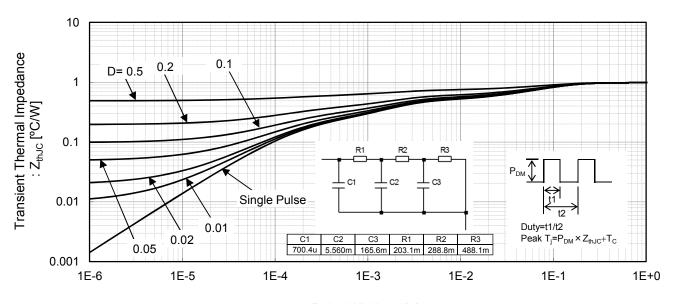
Collector To Emitter Voltage :  $V_{CE}[V]$ 

Fig.16 Typical Gate Charge



#### • Electrical Characteristic Curves

Fig.17 Typical IGBT Transient Thermal Impedance



Pulse Width: t1[s]

## •Inductive Load Switching Circuit and Waveform

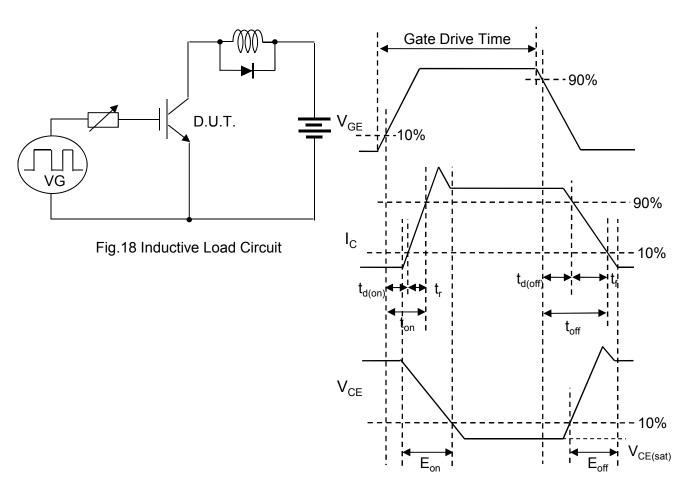


Fig.19 Inductive Load Waveform

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# RGW00TK65 - Web Page

**Distribution Inventory** 

Part Number	RGW00TK65
Package	TO-3PFM
Unit Quantity	450
Minimum Package Quantity	30
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes